

2SB0789ARL Datasheet



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DiGi Electronics Part Number 2SB0789ARL-DG

Manufacturer Panasonic Electronic Components

Manufacturer Product Number 2SB0789ARL

Description TRANS PNP 120V 0.5A MINIP3-F1

Detailed Description Bipolar (BJT) Transistor PNP 120 V 500 mA 120MHz

1 W Surface Mount MiniP3-F1



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Purchase and inquiry

Manufacturer Product Number:	Manufacturer:		
2SB0789ARL	Panasonic Electronic Components		
Series:	Product Status:		
	Obsolete		
Transistor Type:	Current - Collector (Ic) (Max):		
PNP	500 mA		
Voltage - Collector Emitter Breakdown (Max):	Vce Saturation (Max) @ lb, lc:		
120 V	600mV @ 50mA, 500mA		
Current - Collector Cutoff (Max):	DC Current Gain (hFE) (Min) @ lc, Vce:		
	130 @ 150mA, 10V		
Power - Max:	Frequency - Transition:		
1 W	120MHz		
Operating Temperature:	Mounting Type:		
150°C (TJ)	Surface Mount		
Package / Case:	Supplier Device Package:		
TO-243AA	MiniP3-F1		
Base Product Number:			
2SB0789			

Environmental & Export classification

Moisture Sensitivity Level (MSL):	ECCN:
1 (Unlimited)	EAR99
HTSUS:	
8541.29.0075	

2SB0789, 2SB0789A (2SB789, 2SB789A)

Silicon PNP epitaxial planar type

For low-frequency driver amplification

■ Features

- ullet High collector-emitter voltage (Base open) V_{CEO}
- Large collector power dissipation P_C

■ Absolute Maximum Ratings $T_a = 25$ °C

Parameter		Symbol	Rating	Unit
Collector-base voltage	2SB0789	V _{CBO}	-100	V
(Emitter open)	2SB0789A		-120	
Collector-emitter voltage	2SB0789	V _{CEO}	-100	V
(Base open)	2SB0789A		-120	
Emitter-base voltage (Coll	lector open)	V_{EBO}	-5	V
Collector current		I_{C}	- 0.5	A
Peak collector current	I _{CP}	-1	A	
Collector power dissipation	n *	P _C	1	W
Junction temperature	X	Tj	150	°C
Storage temperature		T _{stg}	-55 to +150	°C
Storage temperature		T _{stg}	-55 to +150	°C

Note) *: Print circuit board: Copper foil area of 1 cm² or more, and the board thickness of 1.7 mm for the collector portion.

Unit: mm 4.5±0.1 1.6±0.2 1.5±0.1 1.

Marking Symbol:

• 2SB0789: D

• 2SB0789A: E

■ Electrical Characteristics $T_a = 25$ °C ± 3 °C

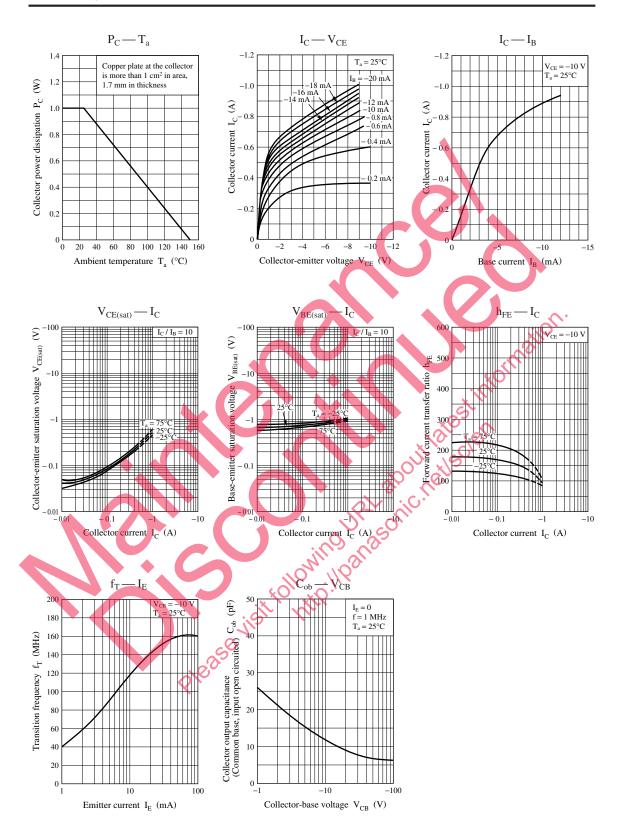
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-emitter voltage 2SB0789	V _{CEO}	$I_C = -100 \text{ pA}, I_B = 0$	-100			V
(Base open) 2SB0789A		6016.0.11.	-120			
Emitter-base voltage (Collector open)	V_{EBO}	$I_{\rm E} = -10 {\rm mA}, I_{\rm C} = 0$	-5			V
Forward current transfer ratio *1	h _{FE1} *2	$V_{CE} = -10 \text{ V}, I_{C} = -150 \text{ mA}$	90		220	_
	h _{FE2}	$V_{CE} = -5 \text{ V}, I_{C} = -500 \text{ mA}$	50			
Collector-emitter saturation voltage *1	V _{CE(sat)}	$I_C = -500 \text{ mA}, I_B = -50 \text{ mA}$		- 0.2	- 0.6	V
Base-emitter saturation voltage *	V _{BE(sat)}	$I_C = -500 \text{ mA}, I_B = -50 \text{ mA}$		- 0.85	-1.20	V
Transition frequency	f_T	$V_{CB} = -10 \text{ V}, I_E = 50 \text{ mA}, f = 200 \text{ MHz}$		120		MHz
Collector output capacitance	C _{ob}	$V_{CB} = -10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$			30	pF
(Common base, input open circuited)						

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

- 2. *1: Pulse measurement
 - *2: Rank classification

Rank	Q	R
h _{FE1}	90 to 155	130 to 220

Note) The part number in the parenthesis shows conventional part number.



2 SJC00056CED

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